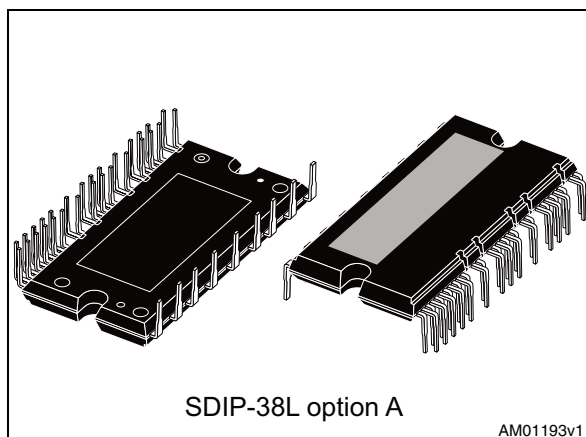


## SLLIMM™ (small low-loss intelligent molded module) IPM, 3-phase inverter, 15 A, 600 V short-circuit rugged IGBT

Datasheet - production data



- 5 kΩ NTC for temperature control
- UL Recognized: UL1557 file E81734

### Applications

- 3-phase inverters for motor drives
- Home appliances, such as washing machines, refrigerators, air conditioners and sewing machines

### Description

These intelligent power modules provides a compact, high performance AC motor drive in a simple, rugged design. Combining ST proprietary control ICs with the most advanced short-circuit-rugged IGBT system technology, this device is ideal for 3-phase inverters in applications such as home appliances and air conditioners. SLLIMM™ is a trademark of STMicroelectronics.

### Features

- IPM 15 A, 600 V 3-phase IGBT inverter bridge including control ICs for gate driving and free-wheeling diodes
- Short-circuit rugged IGBTs
- $V_{CE(sat)}$  negative temperature coefficient
- 3.3 V, 5 V, 15 V CMOS/TTL inputs comparators with hysteresis and pull down/pull up resistors
- Undervoltage lockout
- Internal bootstrap diode
- Interlocking function
- Smart shut down function
- Comparators for fault protection against overtemperature and overcurrent
- Op amps for advanced current sensing
- DBC substrate leading to low thermal resistance
- Isolation rating of 2500 V<sub>rms</sub>/min

Table 1. Device summary

| Order code    | Marking     | Package           | Packaging |
|---------------|-------------|-------------------|-----------|
| STGIPL14K60   | GIPL14K60   | SDIP-38L option A | Tube      |
| STGIPL14K60-S | GIPL14K60-S | SDIP-38L option B | Tube      |

# Contents

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# 1 Internal block diagram and pin configuration

Figure 1. Internal block diagram

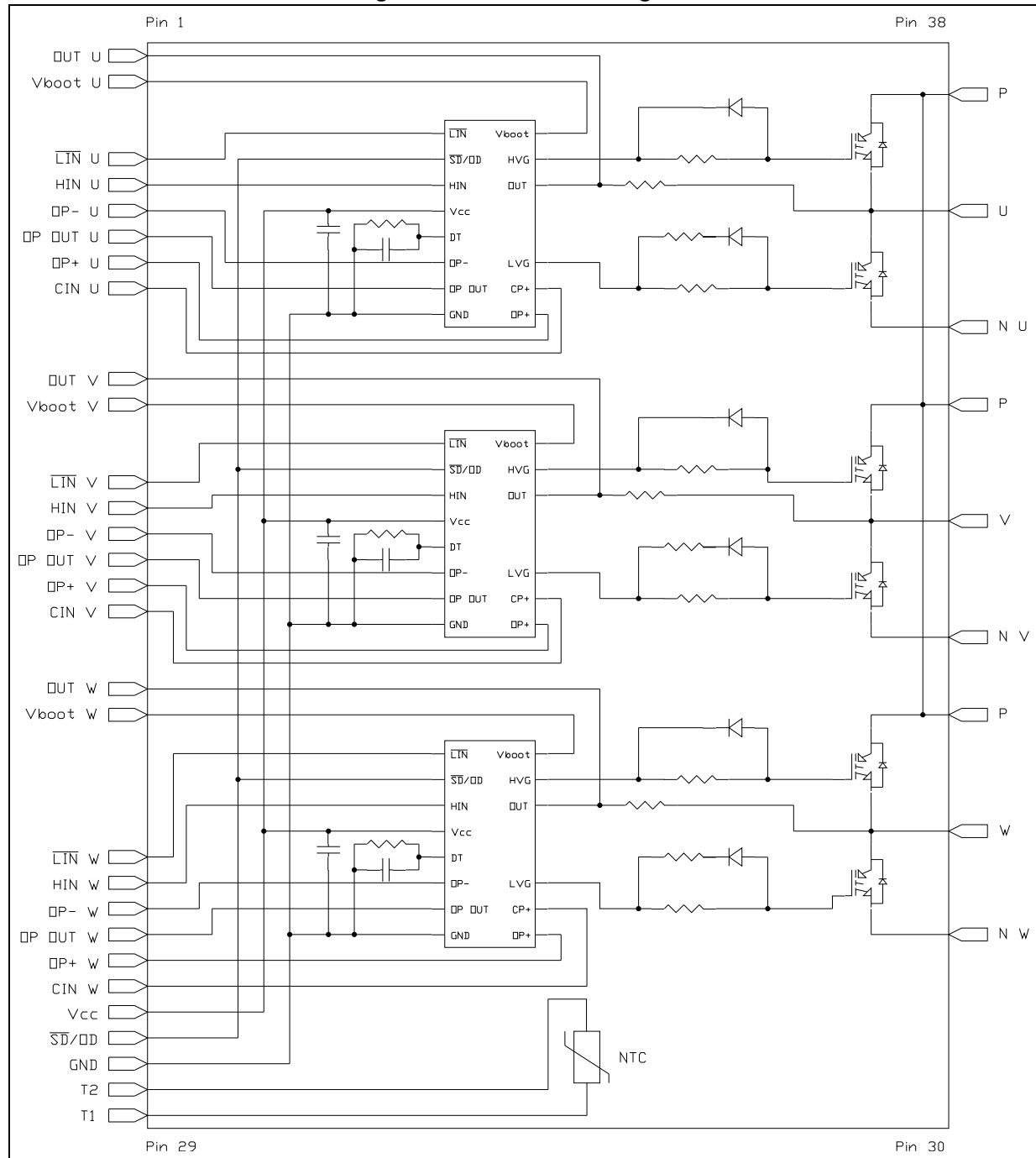


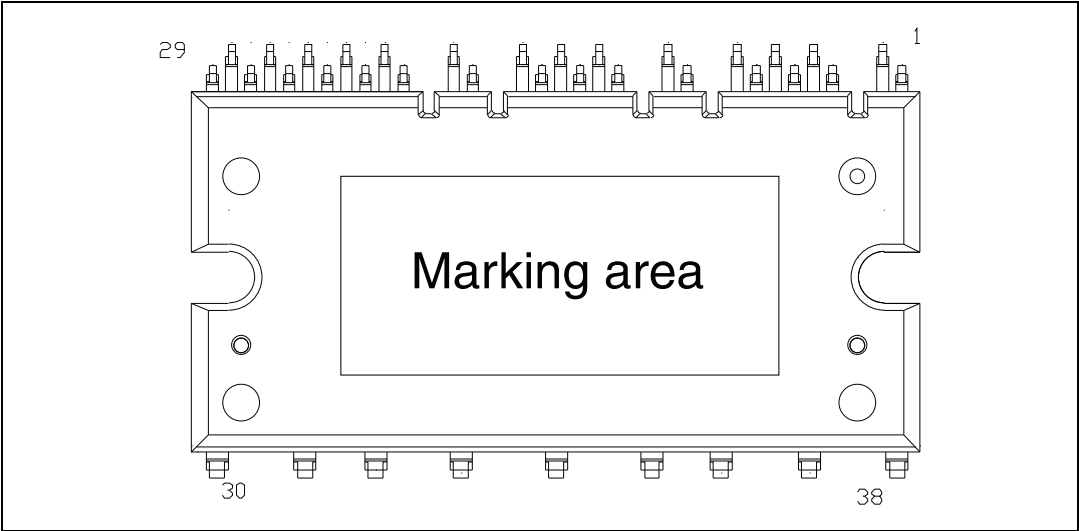
Table 2. Pin description

| Pin | Symbol               | Description                                                         |
|-----|----------------------|---------------------------------------------------------------------|
| 1   | $OUT_U$              | High side reference output for U phase                              |
| 2   | $V_{boot\ U}$        | Bootstrap voltage for U phase                                       |
| 3   | $\overline{LIN}_U$   | Low side logic input for U phase                                    |
| 4   | $HIN_U$              | High side logic input for U phase                                   |
| 5   | $OP^-_U$             | Op amp inverting input for U phase                                  |
| 6   | $OP_{OUT\ U}$        | Op amp output for U phase                                           |
| 7   | $OP^+_U$             | Op amp non inverting input for U phase                              |
| 8   | $CIN_U$              | Comparator input for U phase                                        |
| 9   | $OUT_V$              | High side reference output for V phase                              |
| 10  | $V_{boot\ V}$        | Bootstrap voltage for V phase                                       |
| 11  | $\overline{LIN}_V$   | Low side logic input for V phase                                    |
| 12  | $HIN_V$              | High side logic input for V phase                                   |
| 13  | $OP^-_V$             | Op amp inverting input for V phase                                  |
| 14  | $OP_{OUT\ V}$        | Op amp output for V phase                                           |
| 15  | $OP^+_V$             | Op amp non inverting input for V phase                              |
| 16  | $CIN_V$              | Comparator input for V phase                                        |
| 17  | $OUT_W$              | High side reference output for W phase                              |
| 18  | $V_{boot\ W}$        | Bootstrap voltage for W phase                                       |
| 19  | $\overline{LIN}_W$   | Low side logic input for W phase                                    |
| 20  | $HIN_W$              | High side logic input for W phase                                   |
| 21  | $OP^-_W$             | Op amp inverting input for W phase                                  |
| 22  | $OP_{OUT\ W}$        | Op amp output for W phase                                           |
| 23  | $OP^+_W$             | Op amp non inverting input for W phase                              |
| 24  | $CIN_W$              | Comparator input for W phase                                        |
| 25  | $V_{CC}$             | Low voltage power supply                                            |
| 26  | $\overline{SD} / OD$ | Shut down logic input (active low) / open drain (comparator output) |
| 27  | GND                  | Ground                                                              |
| 28  | $T_2$                | NTC thermistor terminal 2                                           |
| 29  | $T_1$                | NTC thermistor terminal 1                                           |
| 30  | $N_W$                | Negative DC input for W phase                                       |
| 31  | W                    | W phase output                                                      |
| 32  | P                    | Positive DC input                                                   |
| 33  | $N_V$                | Negative DC input for V phase                                       |
| 34  | V                    | V phase output                                                      |

Table 2. Pin description (continued)

| Pin | Symbol         | Description                   |
|-----|----------------|-------------------------------|
| 35  | P              | Positive DC input             |
| 36  | N <sub>U</sub> | Negative DC input for U phase |
| 37  | U              | U phase output                |
| 38  | P              | Positive DC input             |

Figure 2. Pin layout (bottom view)



## 2 Electrical ratings

### 2.1 Absolute maximum ratings

Table 3. Inverter part

| Symbol             | Parameter                                                                                                                                                   | Value | Unit          |
|--------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|---------------|
| $V_{PN}$           | Supply voltage applied between P- $N_U$ , $N_V$ , $N_W$                                                                                                     | 450   | V             |
| $V_{PN(surge)}$    | Supply voltage (surge) applied between P- $N_U$ , $N_V$ , $N_W$                                                                                             | 500   | V             |
| $V_{CES}$          | Each IGBT collector emitter voltage ( $V_{IN}^{(1)} = 0$ )                                                                                                  | 600   | V             |
| $\pm I_C^{(2)}$    | Each IGBT continuous collector current at $T_C = 25^\circ\text{C}$                                                                                          | 15    | A             |
| $\pm I_{CP}^{(3)}$ | Each IGBT pulsed collector current                                                                                                                          | 30    | A             |
| $P_{TOT}$          | Each IGBT total dissipation at $T_C = 25^\circ\text{C}$                                                                                                     | 44    | W             |
| $t_{scw}$          | Short circuit withstand time, $V_{CE} = 0.5 V_{(BR)CES}$<br>$T_j = 125^\circ\text{C}$ , $V_{CC} = V_{boot} = 15\text{ V}$ , $V_{IN(1)} = 0 \div 5\text{ V}$ | 5     | $\mu\text{s}$ |

1. Applied between  $HIN_i$ ,  $\overline{LIN_i}$  and GND for  $i = U, V, W$

2. Calculated according to the iterative formula:

$$I_C(T_C) = \frac{T_{j(max)} - T_C}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_C(T_C))}$$

3. Pulse width limited by max junction temperature

Table 4. Control part

| Symbol        | Parameter                                                            | Min.            | Max.             | Unit |
|---------------|----------------------------------------------------------------------|-----------------|------------------|------|
| $V_{OUT}$     | Output voltage applied between $OUT_U$ , $OUT_V$ , $OUT_W$ - GND     | $V_{boot} - 21$ | $V_{boot} + 0.3$ | V    |
| $V_{CC}$      | Low voltage power supply                                             | - 0.3           | 21               | V    |
| $V_{CIN}$     | Comparator input voltage                                             | - 0.3           | $V_{CC} + 0.3$   | V    |
| $V_{op+}$     | OPAMP non-inverting input                                            | - 0.3           | $V_{CC} + 0.3$   | V    |
| $V_{op-}$     | OPAMP inverting input                                                | - 0.3           | $V_{CC} + 0.3$   | V    |
| $V_{boot}$    | Bootstrap voltage                                                    | - 0.3           | 620              | V    |
| $V_{IN}$      | Logic input voltage applied between $HIN$ , $\overline{LIN}$ and GND | - 0.3           | 15               | V    |
| $V_{SD/OD}$   | Open drain voltage                                                   | - 0.3           | 15               | V    |
| $dV_{OUT}/dt$ | Allowed output slew rate                                             |                 | 50               | V/ns |

Table 5. Total system

| Symbol    | Parameter                                                                                                  | Value      | Unit |
|-----------|------------------------------------------------------------------------------------------------------------|------------|------|
| $V_{ISO}$ | Isolation withstand voltage applied between each pin and heatsink plate (AC voltage, $t = 60\text{sec.}$ ) | 2500       | V    |
| $T_j$     | Power chips operating junction temperature                                                                 | -40 to 150 | °C   |
| $T_C$     | Module case operation temperature                                                                          | -40 to 125 | °C   |

## 2.2 Thermal data

Table 6. Thermal data

| Symbol        | Parameter                                     | Value | Unit |
|---------------|-----------------------------------------------|-------|------|
| $R_{th(j-c)}$ | Thermal resistance junction-case single IGBT  | 2.8   | °C/W |
|               | Thermal resistance junction-case single diode | 5     | °C/W |

### 3 Electrical characteristics

$T_j = 25\text{ °C}$  unless otherwise specified.

**Table 7. Inverter part**

| Symbol                                          | Parameter                                                        | Test condition                                                                                                                                                    | Value |      |      | Unit          |
|-------------------------------------------------|------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|------|------|---------------|
|                                                 |                                                                  |                                                                                                                                                                   | Min.  | Typ. | Max. |               |
| $V_{CE(sat)}$                                   | Collector-emitter saturation voltage                             | $V_{CC} = V_{Boot} = 15\text{ V}$ , $V_{IN}^{(1)} = 0 \div 5\text{ V}$ ,<br>$I_C = 7\text{ A}$                                                                    | -     | 2.1  | 2.5  | V             |
|                                                 |                                                                  | $V_{CC} = V_{Boot} = 15\text{ V}$ , $V_{IN}^{(1)} = 0 \div 5\text{ V}$ ,<br>$I_C = 7\text{ A}$ , $T_j = 125\text{ °C}$                                            | -     | 1.8  |      |               |
| $I_{CES}$                                       | Collector-cut off current<br>( $V_{IN}^{(1)} = 0$ "logic state") | $V_{CE} = 550\text{ V}$<br>$V_{CC} = V_{boot} = 15\text{ V}$                                                                                                      | -     |      | 150  | $\mu\text{A}$ |
| $V_F$                                           | Diode forward voltage                                            | $V_{IN}^{(1)} = 0$ "logic state", $I_C = 7\text{ A}$                                                                                                              | -     |      | 2.1  | V             |
| <b>Inductive load switching time and energy</b> |                                                                  |                                                                                                                                                                   |       |      |      |               |
| $t_{on}$                                        | Turn-on time                                                     | $V_{DD} = 300\text{ V}$ ,<br>$V_{CC} = V_{boot} = 15\text{ V}$ ,<br>$V_{IN}^{(1)} = 0 \div 5\text{ V}$ ,<br>$I_C = 7\text{ A}$<br>(see <a href="#">Figure 3</a> ) | -     | 270  |      | ns            |
| $t_{c(on)}$                                     | Crossover time (on)                                              |                                                                                                                                                                   | -     | 130  |      |               |
| $t_{off}$                                       | Turn-off time                                                    |                                                                                                                                                                   | -     | 320  |      |               |
| $t_{c(off)}$                                    | Crossover time (off)                                             |                                                                                                                                                                   | -     | 110  |      |               |
| $t_{rr}$                                        | Reverse recovery time                                            |                                                                                                                                                                   | -     | 130  |      |               |
| $E_{on}$                                        | Turn-on switching losses                                         |                                                                                                                                                                   | -     | 150  |      | $\mu\text{J}$ |
| $E_{off}$                                       | Turn-off switching losses                                        |                                                                                                                                                                   | -     | 90   |      |               |

1. Applied between  $HINi$   $\overline{LINi}$  and GND for  $i = U, V, W$  ( $\overline{LIN}$  inputs are active-low).

**Note:**  $t_{on}$  and  $t_{off}$  include the propagation delay time of the internal drive.  $t_{C(ON)}$  and  $t_{C(OFF)}$  are the switching time of IGBT itself under the internally given gate driving condition.



Figure 3. Switching time test circuit

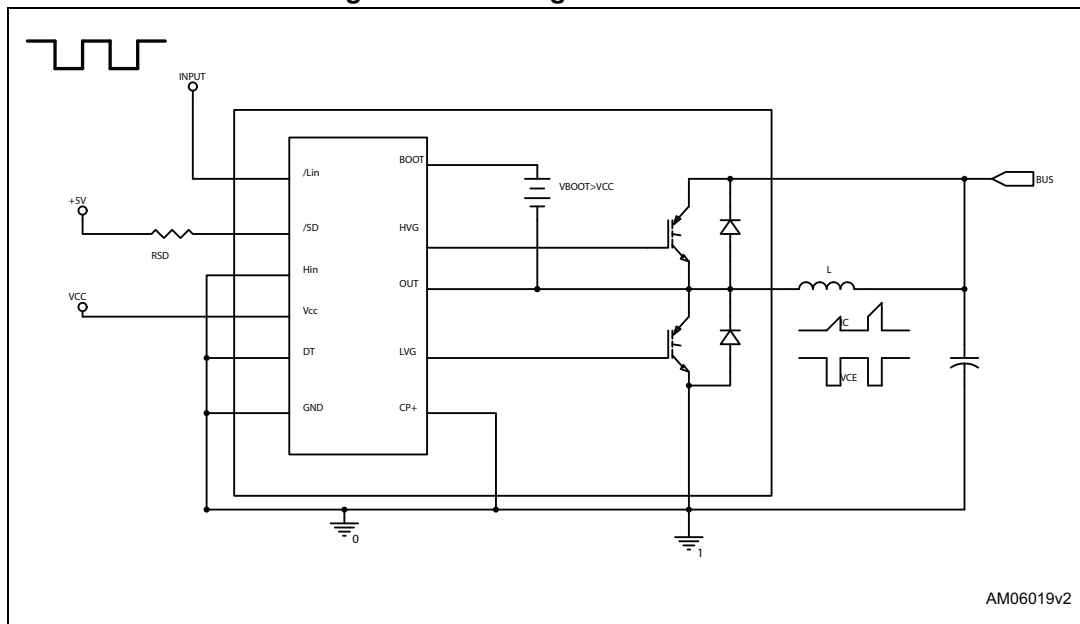


Figure 4. Switching time definition

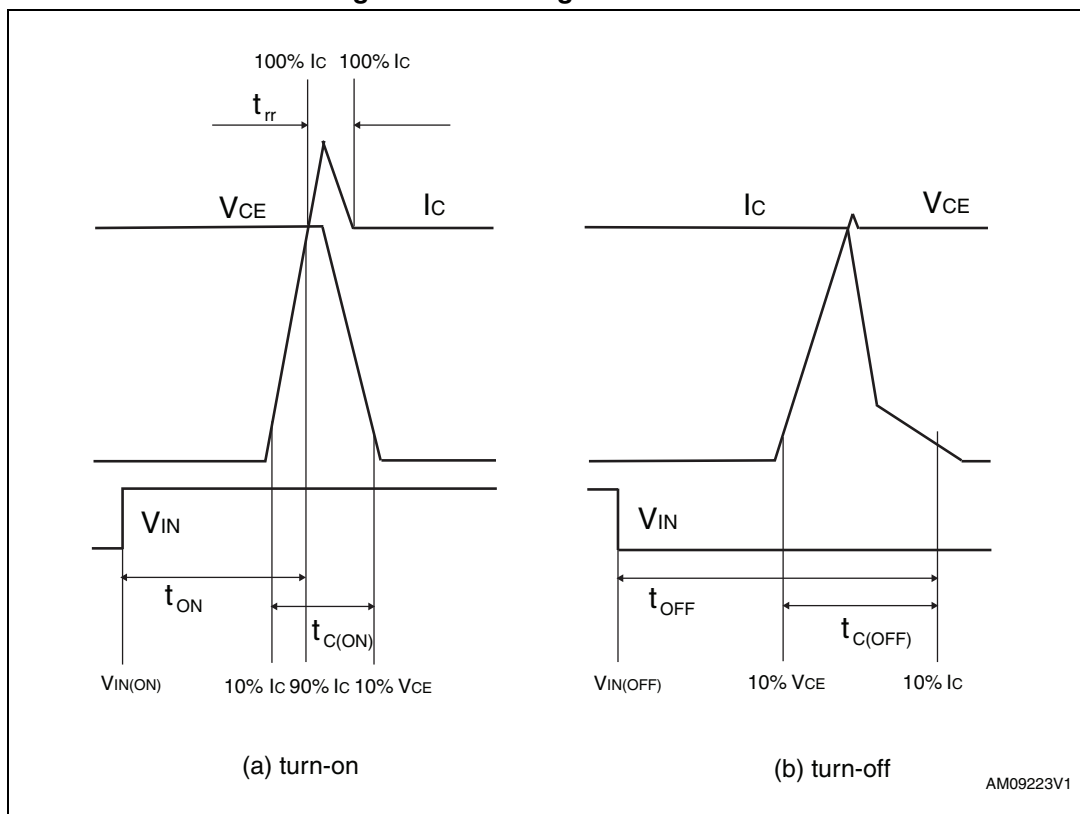


Figure 4 "Switching time definition" refers to HIN inputs (active high). For  $\overline{\text{LIN}}$  inputs (active low),  $V_{\text{IN}}$  polarity must be inverted for turn-on and turn-off.

### 3.1 Control part

**Table 8. Low voltage power supply ( $V_{CC} = 15\text{ V}$  unless otherwise specified)**

| Symbol          | Parameter                                   | Test conditions                                                                                                                       | Min. | Typ. | Max. | Unit          |
|-----------------|---------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{CC\_hys}$   | $V_{CC}$ UV hysteresis                      |                                                                                                                                       | 1.2  | 1.5  | 1.8  | V             |
| $V_{CC\_thON}$  | $V_{CC}$ UV turn ON threshold               |                                                                                                                                       | 11.5 | 12   | 12.5 | V             |
| $V_{CC\_thOFF}$ | $V_{CC}$ UV turn OFF threshold              |                                                                                                                                       | 10   | 10.5 | 11   | V             |
| $I_{qccu}$      | Undervoltage quiescent supply current       | $V_{CC} = 10\text{ V}$<br>$\overline{SD}/\overline{OD} = 5\text{ V}$ ; $\overline{LIN} = 5\text{ V}$ ;<br>$H_{IN} = 0$ , $C_{IN} = 0$ |      |      | 450  | $\mu\text{A}$ |
| $I_{qcc}$       | Quiescent current                           | $V_{CC} = 15\text{ V}$<br>$\overline{SD}/\overline{OD} = 5\text{ V}$ ; $\overline{LIN} = 5\text{ V}$<br>$H_{IN} = 0$ , $C_{IN} = 0$   |      |      | 3.5  | mA            |
| $V_{ref}$       | Internal comparator (CIN) reference voltage |                                                                                                                                       | 0.5  | 0.54 | 0.58 | V             |

**Table 9. Bootstrapped voltage ( $V_{CC} = 15\text{ V}$  unless otherwise specified)**

| Symbol          | Parameter                               | Test conditions                                                                                                                     | Min. | Typ. | Max. | Unit          |
|-----------------|-----------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{BS\_hys}$   | $V_{BS}$ UV hysteresis                  |                                                                                                                                     | 1.2  | 1.5  | 1.8  | V             |
| $V_{BS\_thON}$  | $V_{BS}$ UV turn ON threshold           |                                                                                                                                     | 11.1 | 11.5 | 12.1 | V             |
| $V_{BS\_thOFF}$ | $V_{BS}$ UV turn OFF threshold          |                                                                                                                                     | 9.8  | 10   | 10.6 | V             |
| $I_{QBSU}$      | Undervoltage $V_{BS}$ quiescent current | $V_{BS} < 9\text{ V}$<br>$\overline{SD}/\overline{OD} = 5\text{ V}$ ; $\overline{LIN}$ and<br>$H_{IN} = 5\text{ V}$ ; $C_{IN} = 0$  |      | 70   | 110  | $\mu\text{A}$ |
| $I_{QBS}$       | $V_{BS}$ quiescent current              | $V_{BS} = 15\text{ V}$<br>$\overline{SD}/\overline{OD} = 5\text{ V}$ ; $\overline{LIN}$ and<br>$H_{IN} = 5\text{ V}$ ; $C_{IN} = 0$ |      | 200  | 300  | $\mu\text{A}$ |
| $R_{DS(on)}$    | Bootstrap driver on resistance          | LVG ON                                                                                                                              |      | 120  |      | W             |

**Table 10. Logic inputs ( $V_{CC} = 15\text{ V}$  unless otherwise specified)**

| Symbol     | Parameter                                     | Test conditions                | Min. | Typ. | Max. | Unit          |
|------------|-----------------------------------------------|--------------------------------|------|------|------|---------------|
| $V_{il}$   | Low logic level voltage                       |                                | 0.8  |      | 1.1  | V             |
| $V_{ih}$   | High logic level voltage                      |                                | 1.9  |      | 2.25 | V             |
| $I_{HINh}$ | $H_{IN}$ logic "1" input bias current         | $H_{IN} = 15\text{ V}$         | 110  | 175  | 260  | $\mu\text{A}$ |
| $I_{HINI}$ | $H_{IN}$ logic "0" input bias current         | $H_{IN} = 0\text{ V}$          |      |      | 1    | $\mu\text{A}$ |
| $I_{LINI}$ | $\overline{LIN}$ logic "1" input bias current | $\overline{LIN} = 0\text{ V}$  | 3    | 6    | 20   | $\mu\text{A}$ |
| $I_{LINh}$ | $\overline{LIN}$ logic "0" input bias current | $\overline{LIN} = 15\text{ V}$ |      |      | 1    | $\mu\text{A}$ |
| $I_{SDh}$  | $\overline{SD}$ logic "0" input bias current  | $\overline{SD} = 15\text{ V}$  | 30   | 120  | 300  | $\mu\text{A}$ |

Table 10. Logic inputs ( $V_{CC} = 15\text{ V}$  unless otherwise specified) (continued)

| Symbol    | Parameter                                    | Test conditions              | Min. | Typ. | Max. | Unit          |
|-----------|----------------------------------------------|------------------------------|------|------|------|---------------|
| $I_{SDI}$ | $\overline{SD}$ logic "1" input bias current | $\overline{SD} = 0\text{ V}$ |      |      | 3    | $\mu\text{A}$ |
| Dt        | Dead time                                    | see <a href="#">Figure 9</a> |      | 600  |      | ns            |

Table 11. OPAMP characteristics ( $V_{CC} = 15\text{ V}$  unless otherwise specified)

| Symbol        | Parameter                         | Test condition                                                   | Min. | Typ. | Max. | Unit             |
|---------------|-----------------------------------|------------------------------------------------------------------|------|------|------|------------------|
| $V_{io}$      | Input offset voltage              | $V_{ic} = 0\text{ V}$ , $V_o = 7.5\text{ V}$                     |      |      | 6    | mV               |
| $I_{io}$      | Input offset current              | $V_{ic} = 0\text{ V}$ , $V_o = 7.5\text{ V}$                     |      | 4    | 40   | nA               |
| $I_{ib}$      | Input bias current <sup>(1)</sup> |                                                                  |      | 100  | 200  | nA               |
| $\zeta_{icm}$ | Input common mode voltage range   |                                                                  | 0    |      |      | V                |
| $\zeta_{OL}$  | Low level output voltage          | $R_L = 10\text{ k}\Omega$ to $V_{CC}$                            |      | 75   | 150  | mV               |
| $\zeta_{OH}$  | High level output voltage         | $R_L = 10\text{ k}\Omega$ to GND                                 | 14   | 14.7 |      | V                |
| $I_o$         | Output short circuit current      | $\Sigma\text{output}, \zeta_{id} = +1; \zeta_o = 0\text{ }\zeta$ | 16   | 30   |      | mA               |
|               |                                   | Sink, $\zeta_{id} = -1; \zeta_o = \zeta_{XX}$                    | 50   | 80   |      | mA               |
| SR            | Slew rate                         | $V_i = 1 \div 4\text{ V}$ ; $C_L = 100\text{ pF}$ ; unity gain   | 2.5  | 3.8  |      | V/ $\mu\text{s}$ |
| GBWP          | Gain bandwidth product            | $V_o = 7.5\text{ V}$                                             | 8    | 12   |      | MHz              |
| $A_{vd}$      | Large signal voltage gain         | $R_L = 2\text{ k}\Omega$                                         | 70   | 85   |      | dB               |
| SVR           | Supply voltage rejection ratio    | vs. $V_{CC}$                                                     | 60   | 75   |      | dB               |
| CMRR          | Common mode rejection ratio       |                                                                  | 55   | 70   |      | dB               |

1. The direction of input current is out of the IC.

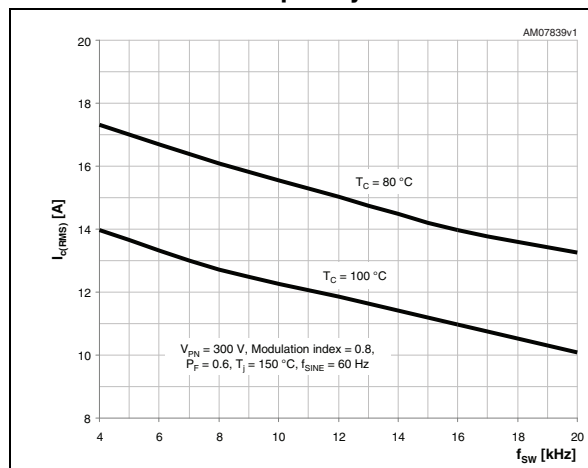
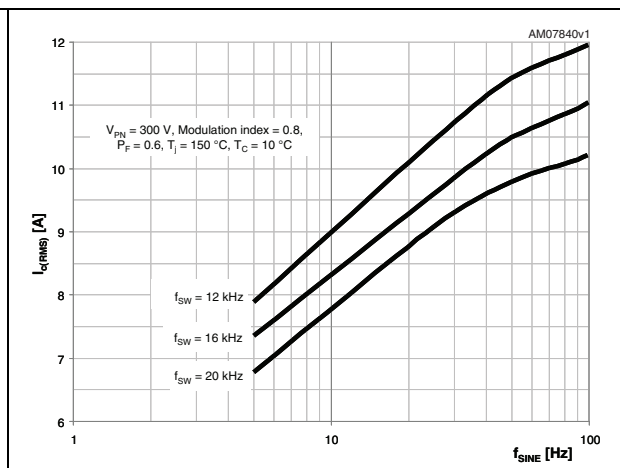
Table 12. Sense comparator characteristics ( $V_{CC} = 15\text{ V}$  unless otherwise specified)

| Symbol        | Parameter                                                                  | Test conditions                                                   | Min. | Typ. | Max. | Unit               |
|---------------|----------------------------------------------------------------------------|-------------------------------------------------------------------|------|------|------|--------------------|
| $I_{ib(i)}$   | Input bias current                                                         | $V_{CIN(i)} = 1\text{ V}$ , $i = U, V \text{ or } W$              | -    |      | 3    | $\mu\text{A}$      |
| $V_{ol}$      | Open-drain low-level output voltage                                        | $I_{od} = 3\text{ mA}$                                            | -    |      | 0.5  | V                  |
| $t_{d\_comp}$ | Comparator delay                                                           | $\overline{SD}/OD$ pulled to 5 V through 100 k $\Omega$ resistor  | -    | 90   | 130  | ns                 |
| SR            | Slew rate                                                                  | $C_L = 180\text{ pF}$ ; $R_{pu} = 5\text{ k}\Omega$               | -    | 60   |      | V/ $\mu\text{sec}$ |
| $t_{sd}$      | Shut down to high / low side driver propagation delay                      | $V_{OUT} = 0$ , $V_{boot} = V_{CC}$ , $V_{IN} = 0$ to 3.3 V       | 50   | 125  | 200  | ns                 |
| $t_{isd}$     | Comparator triggering to high / low side driver turn-off propagation delay | Measured applying a voltage step from 0 V to 3.3 V to pin $CIN_i$ | 50   | 200  | 250  |                    |

Table 13. Truth table

| Condition                                   | Logic input (V <sub>I</sub> ) |     |     | Output |     |
|---------------------------------------------|-------------------------------|-----|-----|--------|-----|
|                                             | $\overline{\text{SD/OD}}$     | LIN | HIN | LVG    | HVG |
| Shutdown enable<br>half-bridge 3-state      | L                             | X   | X   | L      | L   |
| Interlocking<br>half-bridge 3-state         | H                             | L   | H   | L      | L   |
| 0 "logic state"<br>half-bridge 3-state      | H                             | H   | L   | L      | L   |
| 1 "logic state"<br>low side direct driving  | H                             | L   | L   | H      | L   |
| 1 "logic state"<br>high side direct driving | H                             | H   | H   | L      | H   |

Note: X: don't care

Figure 5. Maximum  $I_{C(RMS)}$  current vs. switching frequency <sup>(1)</sup>Figure 6. Maximum  $I_{C(RMS)}$  current vs.  $f_{sine}$  <sup>(1)</sup>

1. Simulated curves refer to typical IGBT parameters and maximum  $R_{thj-c}$ .

### 3.1.1 NTC thermistor

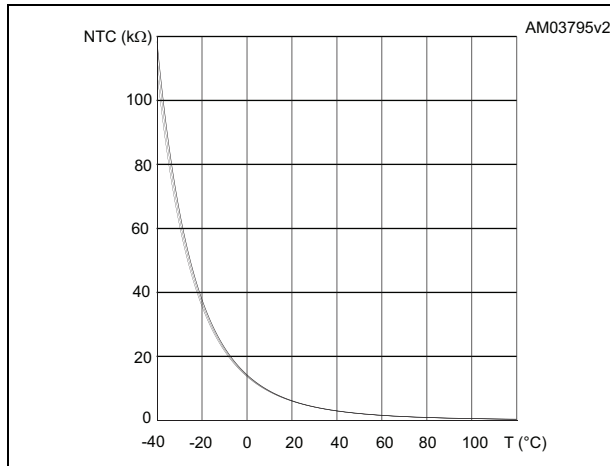
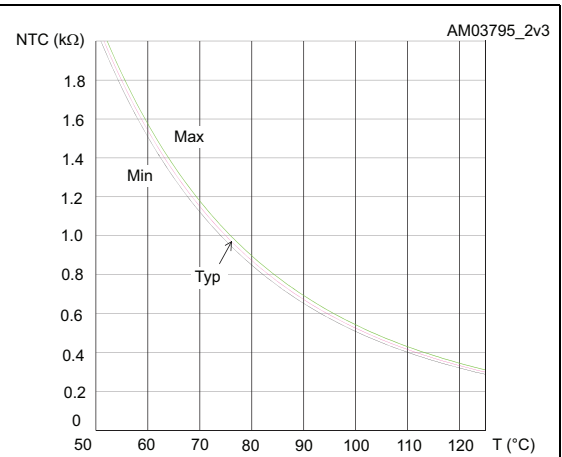
Table 14. NTC thermistor

| Symbol           | Parameter             | Test conditions  | Min. | Typ. | Max. | Unit. |
|------------------|-----------------------|------------------|------|------|------|-------|
| R <sub>25</sub>  | Resistance            | T = 25°C         |      | 5    |      | kΩ    |
| R <sub>125</sub> | Resistance            | T = 125°C        |      | 300  |      | Ω     |
| B                | B-constant            | T = 25°C to 85°C |      | 3340 |      | K     |
| T                | Operating temperature |                  | -40  |      | 125  | °C    |

**Equation 1: resistance variation vs. temperature**

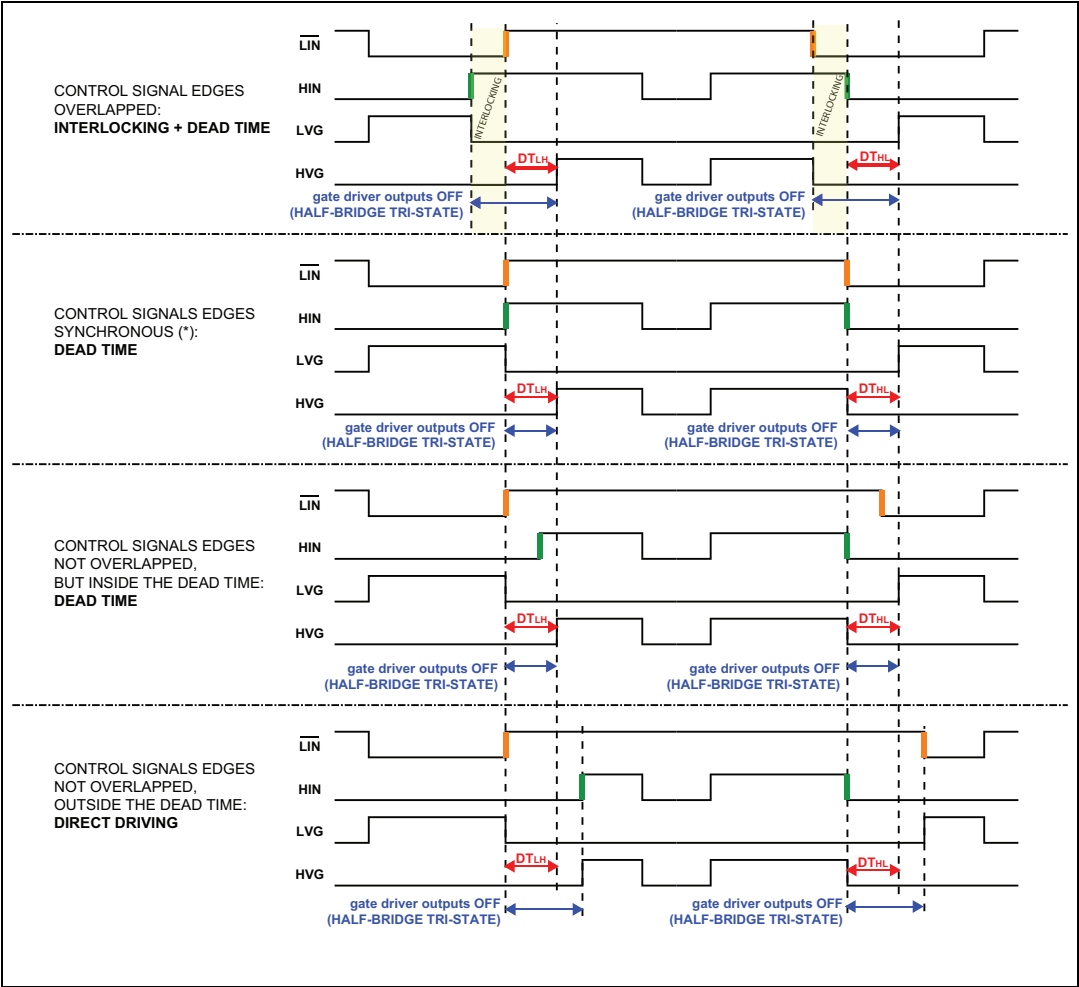
$$R(T) = R_{25} \cdot e^{B\left(\frac{1}{T} - \frac{1}{298}\right)}$$

Where T are temperatures in Kelvin.

**Figure 7. NTC resistance vs. temperature****Figure 8. NTC resistance vs. temperature zoom**

3.2 Waveforms definitions

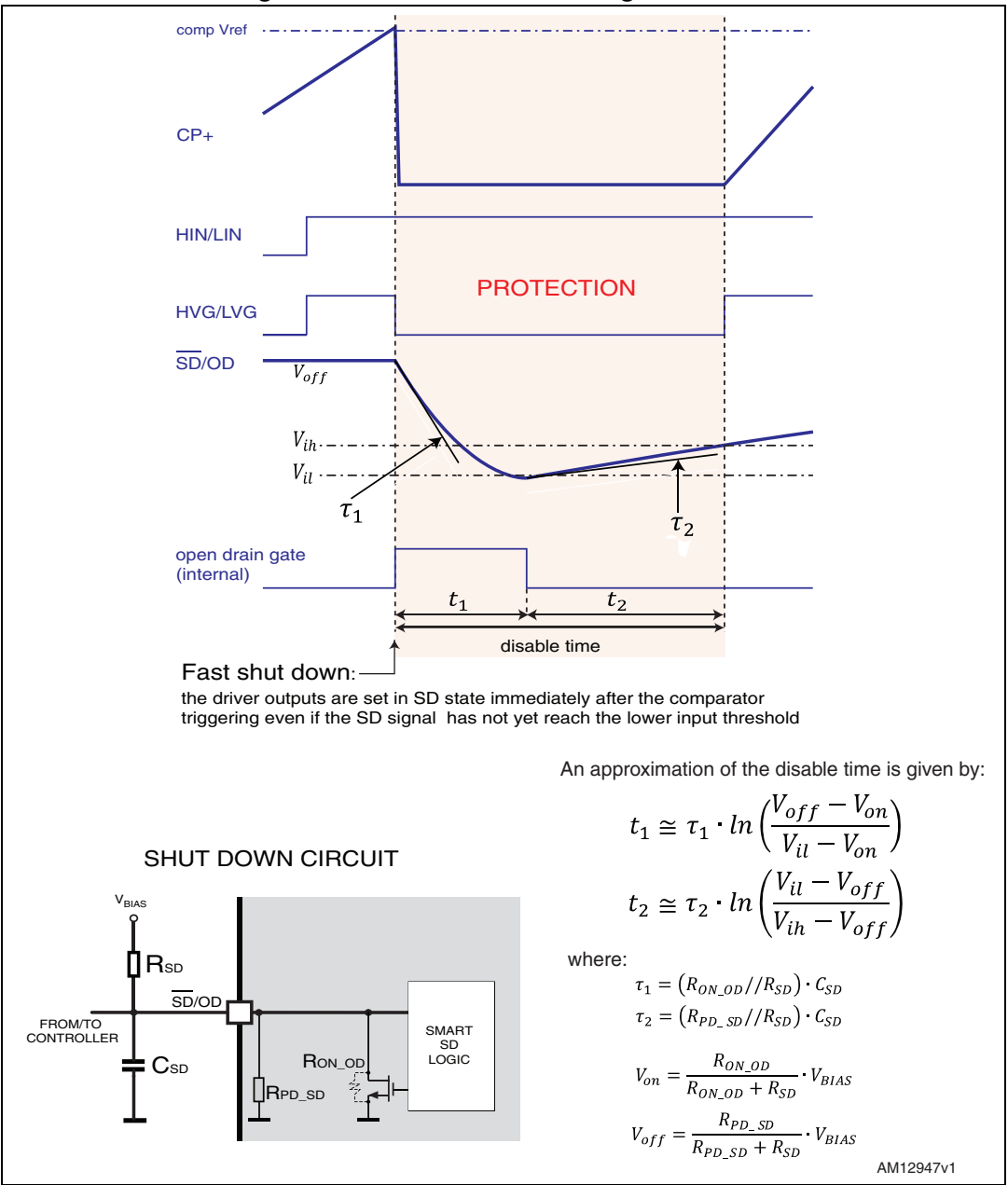
Figure 9. Dead time and interlocking waveforms definitions



## 4 Smart shutdown function

The devices integrate a comparator for fault sensing purposes. The comparator has an internal voltage reference  $V_{REF}$  connected to the inverting input, while the non-inverting input, available on pin (CIN), can be connected to an external shunt resistor in order to implement a simple over-current protection function. When the comparator triggers, the device is set in shutdown state and both its outputs are set to low-level leading the halfbridge in tri-state. In the common overcurrent protection architectures the comparator output is usually connected to the shutdown input through a RC network, in order to provide a mono-stable circuit, which implements a protection time that follows the fault condition. Our smart shutdown architecture allows to immediately turn-off the output gate driver in case of overcurrent, the fault signal has a preferential path which directly switches off the outputs. The time delay between the fault and the outputs turn-off is no more dependent on the RC values of the external network connected to the shutdown pin. At the same time the DMOS connected to the open-drain output (pin SD/OD) is turned on by the internal logic which holds it on until the shutdown voltage is lower than the logic input lower threshold ( $V_{il}$ ). Finally, the smart shutdown function provides the possibility to increase the real disable time without increasing the constant time of the external RC network.

Figure 10. Smart shutdown timing waveforms



Please refer to [Table 12](#) for internal propagation delay time details.





## 5.1 Recommendations

- Input signal HIN is active high logic. A 85k $\Omega$  (typ.) pull down resistor is built-in for each high side input. If an external RC filter is used, for noise immunity, pay attention to the variation of the input signal level.
- Input signal LIN is active low logic. A 720 k $\Omega$  (typ.) pull-up resistor, connected to an internal 5 V regulator through a diode, is built-in for each low side input.
- To prevent the input signals oscillation, the wiring of each input should be as short as possible.
- By integrating an application specific type HVIC inside the module, direct coupling to MCU terminals without any opto-coupler is possible.
- Each capacitor should be located as nearby the pins of IPM as possible.
- Low inductance shunt resistors should be used for phase leg current sensing.
- Electrolytic bus capacitors should be mounted as close to the module bus terminals as possible. Additional high frequency ceramic capacitor mounted close to the module pins will further improve performance.
- The  $\overline{\text{SD}}/\text{OD}$  signal should be pulled up to 5 V / 3.3 V with an external resistor (see [Section 4: Smart shutdown function](#) for detailed info).

**Table 15. Recommended operating conditions**

| Symbol            | Parameter                          | Conditions                                                           | Value |      |      | Unit          |
|-------------------|------------------------------------|----------------------------------------------------------------------|-------|------|------|---------------|
|                   |                                    |                                                                      | Min.  | Typ. | Max. |               |
| V <sub>PN</sub>   | Supply Voltage                     | Applied between P-Nu, Nv, Nw                                         |       | 300  | 400  | V             |
| V <sub>CC</sub>   | Control supply voltage             | Applied between V <sub>CC</sub> -GND                                 | 13.5  | 15   | 18   | V             |
| V <sub>BS</sub>   | High side bias voltage             | Applied between V <sub>BOOTi</sub> -OUT <sub>i</sub> for i = U, V, W | 13    |      | 18   | V             |
| t <sub>dead</sub> | Blanking time to prevent Arm-short | For each input signal                                                | 1     |      |      | $\mu\text{s}$ |
| f <sub>PWM</sub>  | PWM input signal                   | -40°C < T <sub>C</sub> < 100°C<br>-40°C < T <sub>J</sub> < 125°C     |       |      | 20   | kHz           |
| T <sub>C</sub>    | Case operation temperature         |                                                                      |       |      | 100  | °C            |

*Note:* For further details refer to AN3338.

## 6 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

Please refer to dedicated technical note TN0107 for mounting instructions.

**Table 16. SDIP-38L option A mechanical data**

| Dimensions | mm.   |       |       |
|------------|-------|-------|-------|
|            | Min.  | Typ.  | Max.  |
| A          | 49.10 | 49.60 | 50.10 |
| A1         | 1.10  | 1.30  | 1.50  |
| A2         | 1.40  | 1.60  | 1.80  |
| A3         | 44.10 | 44.60 | 45.10 |
| B          | 24.00 | 24.50 | 25.00 |
| B1         | 11.25 | 11.85 | 12.45 |
| B2         | 27.10 | 27.60 | 28.10 |
| B3         | 28.60 | 29.10 | 29.60 |
| C          | 5.00  | 5.40  | 6.00  |
| C1         | 6.50  | 7.00  | 7.50  |
| C2         | 10.35 | 10.85 | 11.35 |
| e          | 1.10  | 1.30  | 1.50  |
| e1         | 3.20  | 3.40  | 3.60  |
| e2         | 5.80  | 6.00  | 6.20  |
| e3         | 4.60  | 4.80  | 5.00  |
| e4         | 5.60  | 5.80  | 6.00  |
| e5         | 6.30  | 6.50  | 6.70  |
| e6         | 4.50  | 4.70  | 4.90  |
| D          |       | 38.10 |       |
| D1         |       | 5.75  |       |
| E          |       | 11.80 |       |
| E1         |       | 2.15  |       |
| F          | 0.85  | 1.00  | 1.15  |
| F1         | 0.35  | 0.50  | 0.65  |
| R          | 1.55  | 1.75  | 1.95  |
| T          | 0.45  | 0.55  | 0.65  |
| V          | 0°    |       | 6°    |

Figure 12. SDIP-38L option A drawing dimensions

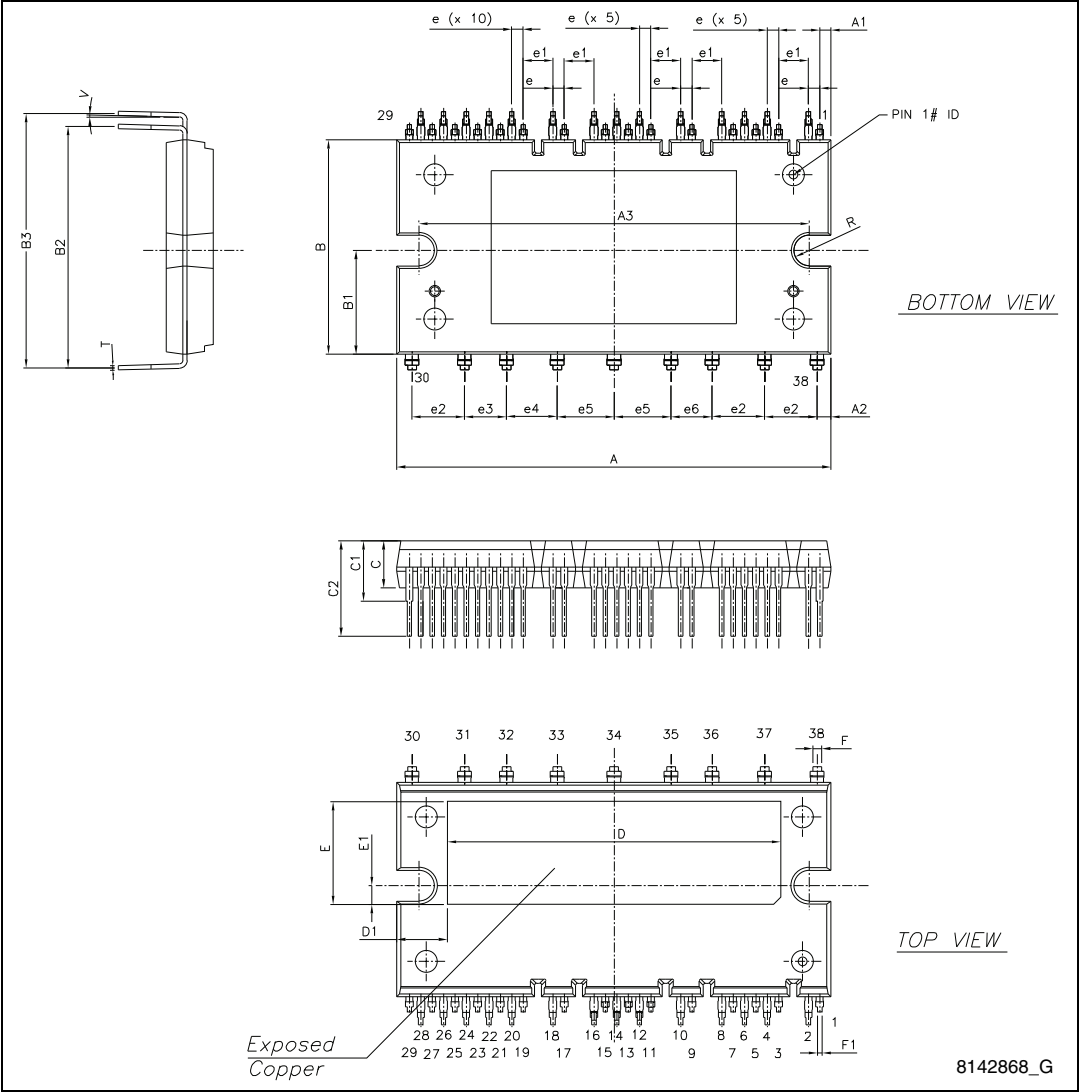
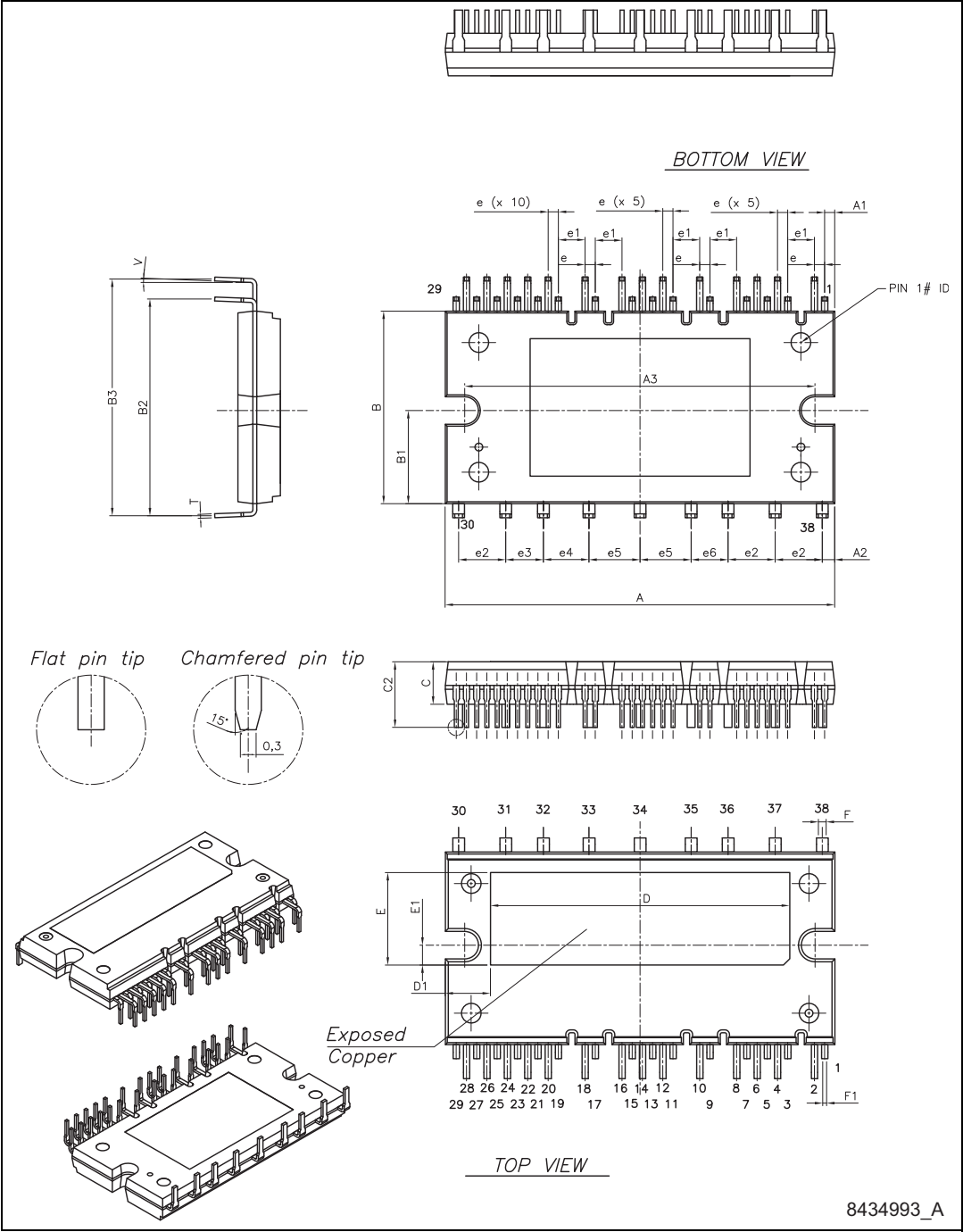


Table 17. SDIP-38L option B mechanical data

| Dimensions | mm.   |       |       |
|------------|-------|-------|-------|
|            | Min.  | Typ.  | Max.  |
| A          | 49.10 | 49.60 | 50.10 |
| A1         | 1.10  | 1.30  | 1.50  |
| A2         | 1.40  | 1.60  | 1.80  |
| A3         | 44.10 | 44.60 | 45.10 |
| B          | 24.00 | 24.50 | 25.00 |
| B1         | 11.25 | 11.85 | 12.45 |
| B2         | 27.10 | 27.60 | 28.10 |
| B3         | 29.65 | 30.15 | 30.65 |
| C          | 5.00  | 5.40  | 6.00  |
| C2         | 8.15  | 8.35  | 8.55  |
| e          | 1.10  | 1.30  | 1.50  |
| e1         | 3.20  | 3.40  | 3.60  |
| e2         | 5.80  | 6.00  | 6.20  |
| e3         | 4.60  | 4.80  | 5.00  |
| e4         | 5.60  | 5.80  | 6.00  |
| e5         | 6.30  | 6.50  | 6.70  |
| e6         | 4.50  | 4.70  | 4.90  |
| D          |       | 38.10 |       |
| D1         |       | 5.75  |       |
| E          |       | 11.80 |       |
| E1         |       | 2.15  |       |
| F          | 0.85  | 1.00  | 1.15  |
| F1         | 0.35  | 0.50  | 0.65  |
| R          | 1.55  | 1.75  | 1.95  |
| T          | 0.45  | 0.55  | 0.65  |
| V          | 0°    |       | 6°    |

Figure 13. SDIP-38L option B drawing dimensions



7      Packaging mechanical data

Figure 14. SDIP-38L shipping tube type A (dimensions are in mm.)

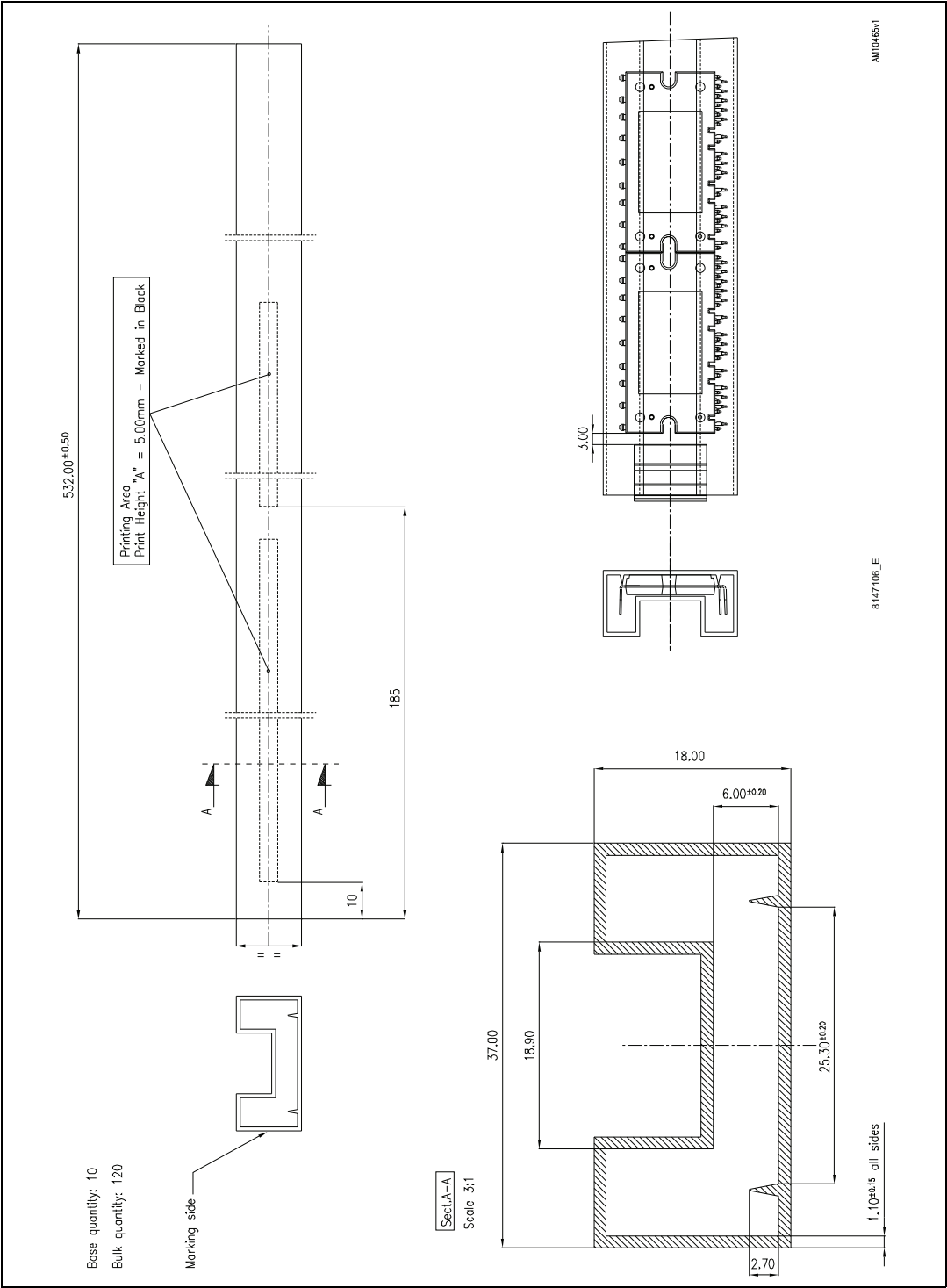
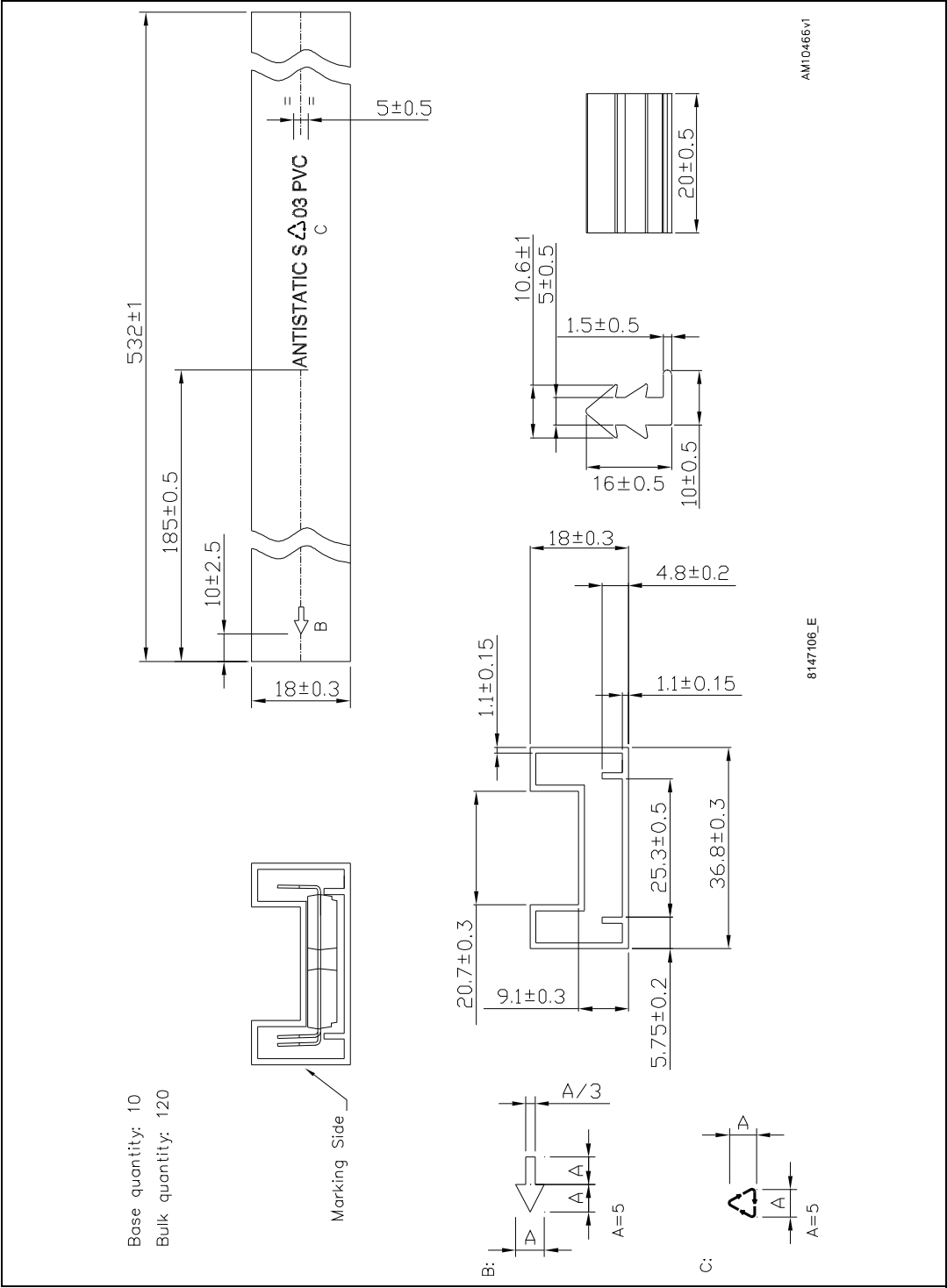


Figure 15. SDIP-38L shipping tube type B (dimensions are in mm.)





## 8 Revision history

**Table 18. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                           |
|-------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 16-Apr-2009 | 1        | Initial release                                                                                                                                                                                                                                                                   |
| 29-Mar-2010 | 2        | Inserted <a href="#">Figure 5</a> , <a href="#">Figure 6</a> and <a href="#">Section 4: Smart shutdown function</a> .<br>Updated <a href="#">Section 3.1: Control part</a> and package mechanical data, <a href="#">Section 6</a> .<br>Minor text changes to improve readability. |
| 14-Jun-2010 | 3        | Document status promoted from preliminary data to datasheet.<br>Updated <a href="#">Table 7: Inverter part</a> , <a href="#">Figure 5: Maximum IC(RMS) current vs. switching frequency</a> and <a href="#">Figure 6: Maximum IC(RMS) current vs. fsine(1)</a> .                   |
| 21-Sep-2010 | 4        | Updated: <a href="#">Table 3</a> , <a href="#">5</a> , <a href="#">8</a> , <a href="#">9</a> , <a href="#">10</a> and <a href="#">12</a> .<br>Modified: <a href="#">Figure 5</a> and <a href="#">Figure 6</a> .                                                                   |
| 09-Mar-2011 | 5        | Updated title with SLLIMM™ in cover page, added SDIP-38L tube dimensions <a href="#">Figure 14</a> .                                                                                                                                                                              |
| 04-Nov-2011 | 6        | Updated title with SLLIMM™ (small low-loss intelligent molded module) IPM, 3-phase inverter - 15 A, 600 V short-circuit rugged IGBT in cover page and SDIP-38L mechanical data <a href="#">Table 16 on page 19</a> , <a href="#">Figure 12</a> .                                  |
| 28-Aug-2012 | 7        | Modified: Min. and Max. value <a href="#">Table 4 on page 6</a> .<br>Updated: <a href="#">Figure 14</a> .<br>Added: <a href="#">Figure 15</a> .                                                                                                                                   |
| 04-Mar-2013 | 8        | Added: <a href="#">Figure 7</a> and <a href="#">Figure 8</a>                                                                                                                                                                                                                      |
| 13-Mar-2013 | 9        | Modified: <a href="#">Figure 8 on page 13</a>                                                                                                                                                                                                                                     |
| 17-Jun-2013 | 10       | Updated: <a href="#">Figure 9: Dead time and interlocking waveforms definitions</a> .                                                                                                                                                                                             |
| 17-Oct-2013 | 11       | Added device STGIPL14K60-S and modified <a href="#">Table 1: Device summary</a> accordingly.<br>Updated <a href="#">Section 6: Package information</a> and <a href="#">Section 7: Packaging mechanical data</a> .<br>Minor text changes.                                          |

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